

# Schottky Barrier Rectifier

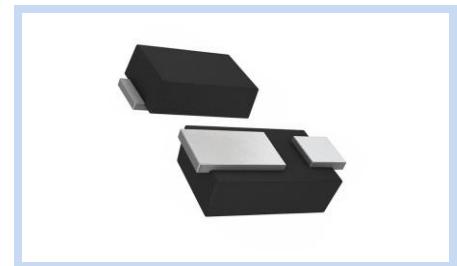
## 1A 60V SOD-323T

SD16WST

MERITEK

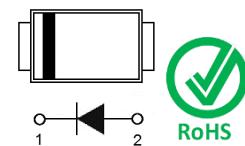
### FEATURE

- High-Speed Switching
- Low Forward Voltage Drop
- PN Junction Guard Ring for Transient and ESD Protection
- Applications: DC-DC Converter, Polarity Protection, Switch Mode Power Supply,



### MECHANICAL DATA

- Case: SOD-323T Package, Epoxy Molded Meets UL 94V-0
- Terminals: Solderable per MIL-STD-750, Method 2026
- Polarity: Color Band Denotes Cathode End



### MAXIMUM RATINGS

| Parameter, $T_A=25^\circ\text{C}$   | Symbol         | Value       | Unit |
|---|----------------|-------------|------|
| Maximum Recurrent Peak Reverse Voltage  | $V_{RRM}$      | 60          | V    |
| Maximum RMS Voltage   | $V_{RMS}$      | 42          | V    |
| Maximum DC Blocking Voltage   | $V_{DC}$       | 60          | V    |
| Maximum Average Forward Rectified Current   | $I_{F(AV)}$    | 1           | A    |
| Peak Forward Surge Current<br>8.3ms Single Half-Sinewave Superimposed on Rated Load | $I_{FSM}$      | 22          | A    |
| Typical Thermal Resistance, Junction to Ambient                                     | $R_{θJA}$      | 173         | °C/W |
| Operating Junction and Storage Temperature Range                                    | $T_J, T_{STG}$ | -65 to +150 | °C   |

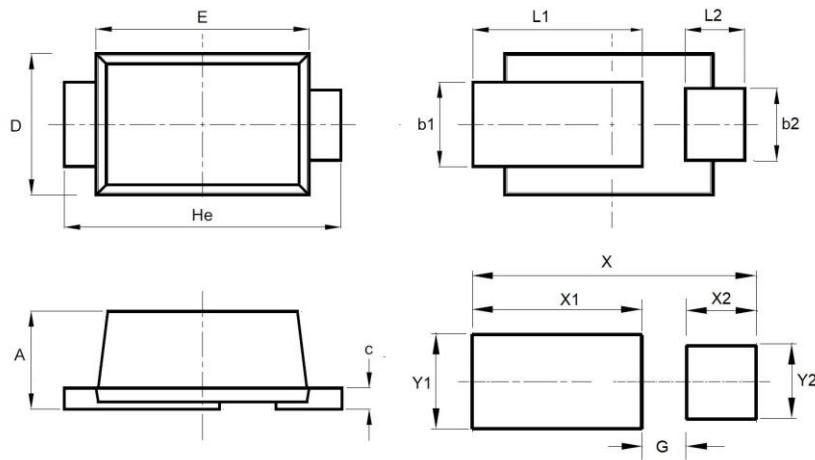
### ELECTRICAL CHARACTERISTICS

| Parameter, $T_A=25^\circ\text{C}$ | Symbol                                 | Min. | Typ. | Max. | Unit |
|-----------------------------------|--|------|------|------|------|
| Reverse Breakdown Voltage         | $V_{BR}$                               | 60   | --   | --   | V    |
| Maximum Forward Voltage           | $I_F=0.1\text{mA}$                     | --   | --   | 0.45 | V    |
|                                   | $I_F=0.7\text{mA}$                     | --   | --   | 0.58 |      |
|                                   | $I_F=1\text{A}$                        | --   | --   | 0.64 |      |
| Maximum Reverse Current           | $I_R$                                  | --   | --   | 5    | μA   |
|                                   | $I_R=60\text{V}, T_J=25^\circ\text{C}$ | --   | --   | 100  |      |
| Junction Capacitance              | $C_T$                                  | --   | 38   | --   | pF   |

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

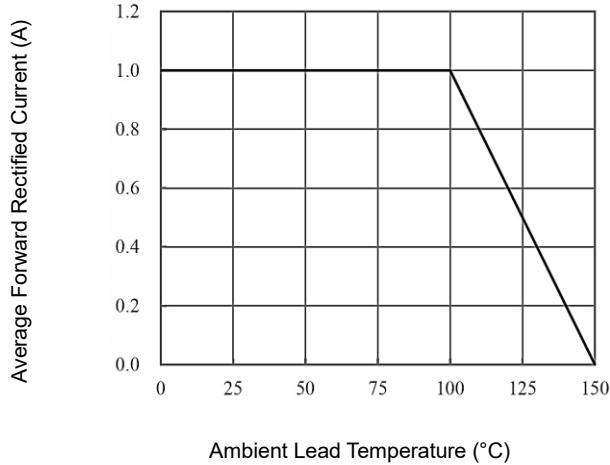
### DIMENSIONS

| Item | Min. (mm) | Max. (mm) |
|------|-----------|-----------|
| A    | 0.50      | 0.70      |
| b1   | 0.75      | 0.95      |
| b2   | 0.50      | 0.70      |
| c    | 0.10      | 0.20      |
| D    | 1.15      | 1.35      |
| E    | 1.80      | 2.00      |
| He   | 2.40      | 2.60      |
| L2   | 0.40      | 0.60      |
| C    | 1.30      | 1.50      |
| G    |           | 0.50      |
| X    |           | 3.30      |
| X1   |           | 2.00      |
| X2   |           | 0.80      |
| Y1   |           | 1.10      |
| Y2   |           | 1.00      |

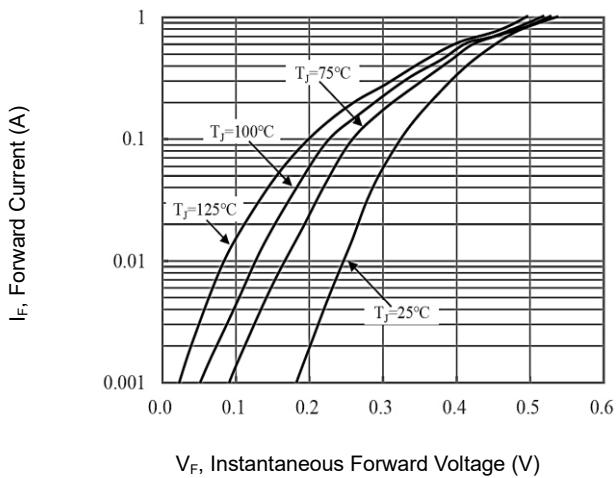


## CHARACTERISTIC CURVES

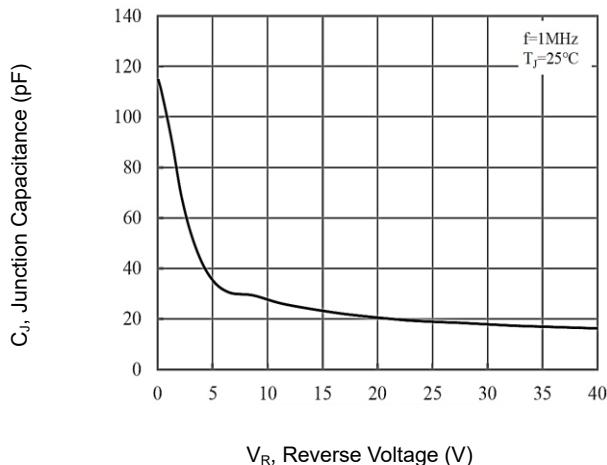
Typical Forward Current Derating Curve



Typical Forward Characteristics



Typical Junction Capacitance



Typical Reverse Characteristics

